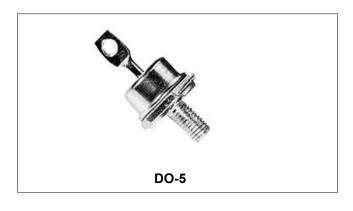






# 50HQ035/50HQ040/50HQ045 SCHOTTKY RECTIFIER



#### **Features**

- 150 °C T<sub>J</sub> operation
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

### **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	-	35(50HQ035) 40(50HQ040) 45(50HQ045)	V
Average Rectified Forward Current	I <sub>F (AV)</sub>	50% duty cycle @Tc=101°C, rectangular wave form	60	Α
Peak One Cycle Non-Repetitive Surge Current	I <sub>FSM</sub>	10 ms, Half Sine pulse, T <sub>C</sub> = 25 °C	1150	Α

#### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V <sub>F1</sub>	@ 60A, Pulse, T <sub>J</sub> = 25 °C	-	0.60	V
	V F1	@ 120A, Pulse, T <sub>J</sub> = 25 °C	-	0.78	V
	$V_{F2}$	@ 60A, Pulse, T <sub>J</sub> = 125 °C	-	0.53	V
	V F2	@ 120A, Pulse, T <sub>J</sub> = 125 °C	-	0.69	V
Reverse Current*	I= .	@V <sub>R</sub> = rated V <sub>R</sub>		5	mA
	I <sub>R1</sub>	T <sub>J</sub> = 25 °C	-	3	IIIA
	I <sub>R2</sub>	$@V_R = rated V_R$		200	mA
	IR2	T <sub>J</sub> = 125 °C		200	ША
Junction Capacitance	C <sub>⊤</sub>	@V <sub>R</sub> = 5V, T <sub>C</sub> = 25 °C	_	2600	pF
	01	f <sub>SIG</sub> = 1MHz		2000	Ρı
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

 $<sup>^{\</sup>star}$  Pulse width < 300  $\mu$ s, duty cycle < 2%







## **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	R <sub>0</sub> JC	DC operation	0.83	°C/W
Typical Thermal Resistance, case to Heat Sink	$R_{ heta cs}$	Mounting surface, smooth and greased	0.25	°C/W
Mounting Torque Min.	т	Non-lubricated threads	23	Kg-cm
Max.	T <sub>M</sub>		46	
Approximate Weight	wt	-	15	g

### **Ratings and Characteristics Curves**

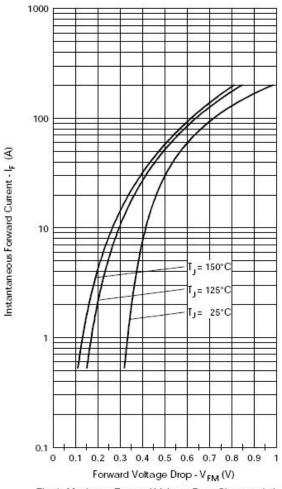


Fig. 1-Maximum Forward Voltage Drop Characteristics

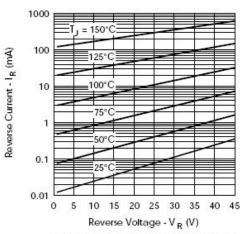


Fig. 2-Typical Values of Reverse Current Vs. Reverse Voltage

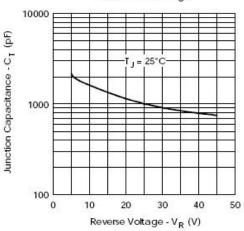


Fig. 3-Typical Junction Capacitance Vs. Reverse Voltage

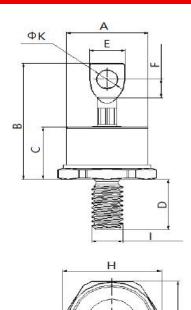
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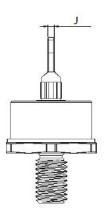






#### **Mechanical Dimensions DO-5**





SYMBOL	Millimeters		
	Min.	Max.	
ФА	15.0		
В	-	25.4	
С	9.4	10.2	
D	11.0		
E	6.1	6.7	
F	3.0	-	
G	17.3		
Н	19.0		
I	M6		
J	0.9	1.5	
ФК			

# **Ordering Information:**

Device	Package	Shipping	
50HQ035(040)(045)	DO-5(Pb-Free)	100pcs / box	

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

## **Marking Diagram**



Where XXXXX is YYWWL

50HQ035 = Part name YY = Year WW = Week L = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0







#### DISCLAIMER:

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